TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π -MOSIII)

2SK2605

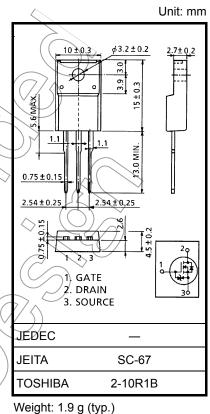
Switching Regulator Applications

•	Low drain-source ON resistance	: R _{DS (ON)} = 1.9 Ω (typ.)
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- High forward transfer admittance $: |Y_{fs}| = 3.8 \text{ S (typ.)}$
- Low leakage current : I_{DSS} = 100 μA (max) (V_{DS} = 640 V)
- Enhancement mode : V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteris	tics	Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	800	$(\mathcal{M} \wedge)^{\sim}$
Drain-gate voltage (Rc	_{SS} = 20k Ω)	V _{DGR}	800	V V
Gate-source voltage		V _{GSS}	±30	V
Drain current	DC (Note 1)	I _D	5	Ā
Drain current	Pulse (Note 1)	I _{DP}	15	Ă
Drain power dissipation	n (Tc = 25°C)	PD	45	w
Single pulse avalanche	e energy (Note 2)	E _{AS}	370	mJ
Avalanche current		IAR	5	A
Repetitive avalanche e	nergy (Note 3)	EAR) 4.5	mJ
Channel temperature		Tch	150 <	°C
Storage temperature ra	inge	T _{stg}	-55 to 150)°C



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	Rth (ch-c)	2.78	°C / W
Thermal resistance, channel to ambient	Rth (ch-a)	62.5	°C / W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 27 mH, R_G = 25 Ω , I_{AR} = 5 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.

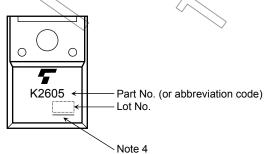
Electrical Characteristics (Ta = 25°C)

Charao	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	urrent	I _{GSS}	V _{GS} = ±30 V, V _{DS} = 0 V	_	—	±10	μA
Gate-source br	eakdown voltage	V (BR) GSS	I _G = ±10 μA, V _{DS} = 0 V	±30	_	_	V
Drain cut-off cu	rrent	I _{DSS}	V _{DS} = 640 V, V _{GS} = 0 V	Ŋ	_	100	μA
Drain-source br	reakdown voltage	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	800		_	V
Gate threshold	voltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	2.0	-7(4.0	V
Drain-source O	N resistance	R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3 \text{ A},$		1.9	2.2	Ω
Forward transfe	r admittance	Y _{fs}	V _{DS} = 15 V, I _D = 3 A	<u>).</u> 0	3.8	_	S
Input capacitance Reverse transfer capacitance		C _{iss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz		1080		pF
		C _{rss}			16		
Output capacitance		C _{oss}			105	1	
	Rise time	tr	$V_{GS_{0V}}^{10V} \prod_{ID=3A}^{ID=3A} V_{out}$	- (40		
Cultobing time	Turn-on time	t _{on}	\sim	N)	80) —	
Switching time	Fall time	t _f		$\langle \hat{\boldsymbol{\nabla}} \rangle$	40	_	ns
	Turn-off time	t _{off}	$V_{DD} = 200V$ Duty $\leq 1\%$, $t_W = 10\mu s$) -	140		
Total gate charg plus gate-drain)		Qg		_	34	_	
Gate-source charge		Q _{gs}	$V_{DD} \approx 400^{\circ} V, V_{GS} = 10 V, V_{D} = 5 A$	_	16	—	nC
Gate−drain ("miller") Charge		Qgd		_	18	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)			_	_	5	A
Pulse drain reverse current (Note 1)		-			15	A
Forward voltage (diode)	VDSF	I _{DR} = 5 A, V _{GS} = 0 V		-	-1.9	V
Reverse recovery time	t _{rr}	I _{DR} = 5 A, V _{GS} = 0 V, dI _{DR} / dt = 100 A / μs		1000		ns
Reverse recovery charge	Qrr	$DR = 3 A$, $vGS = 0 v$, $dDR / dt = 100 A / \mu S$	_	7.5	_	μC

Marking



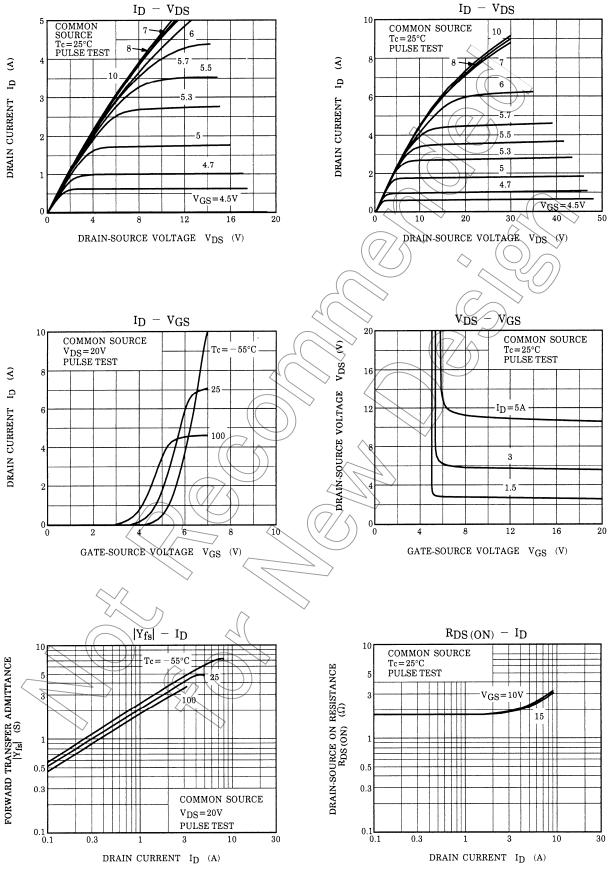
Note 4: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

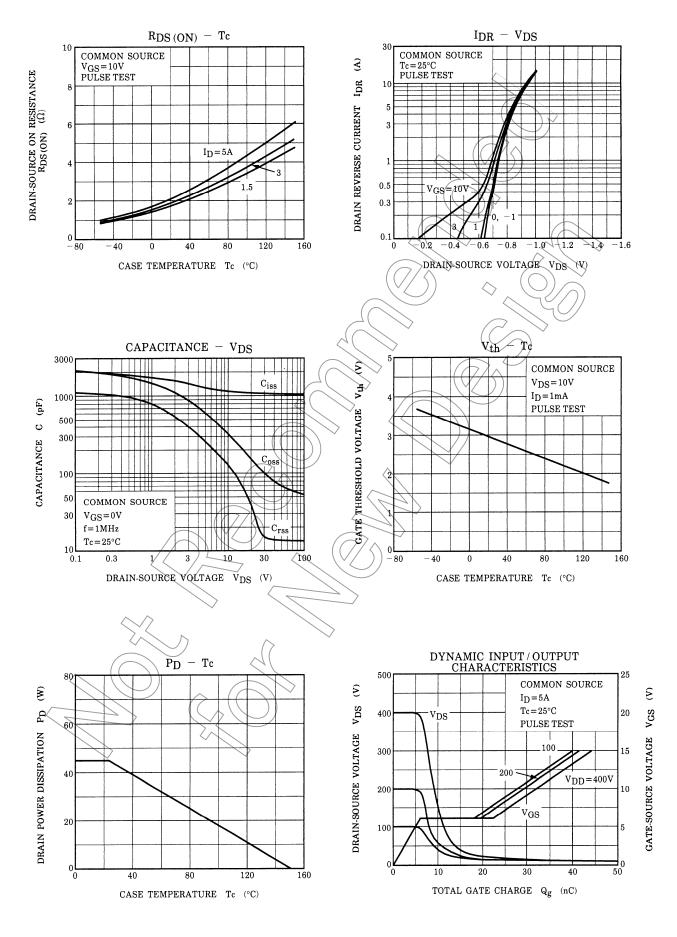
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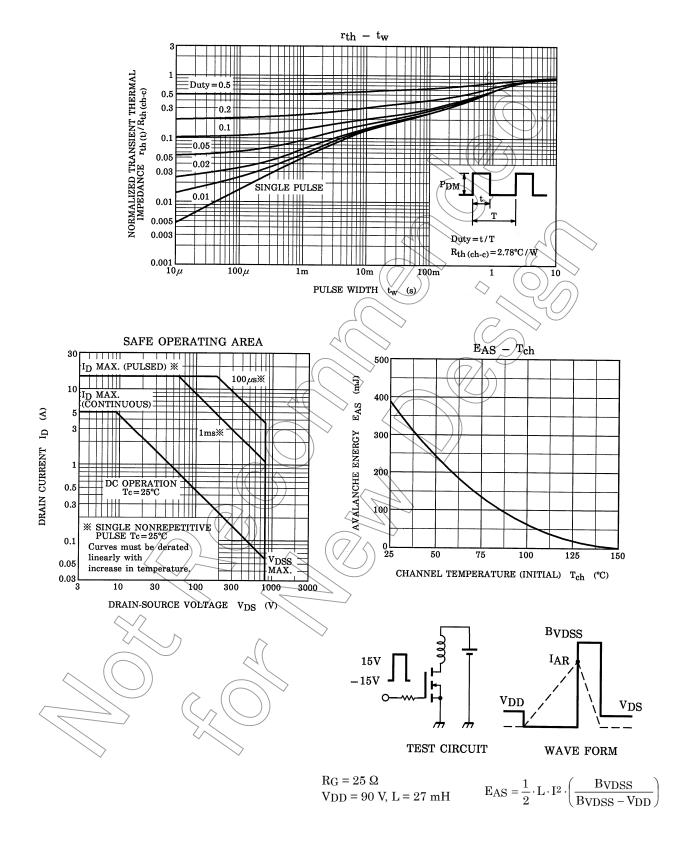
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